Features

40 to 200 MHz
7.0 mm x 5.0 mm x 1.8 mm ceramic SMD
Compact and lightweight
Differential LVDS Outputs
2.5 or 3.3 v supply
0.3 ps integrated phase jitter typ.

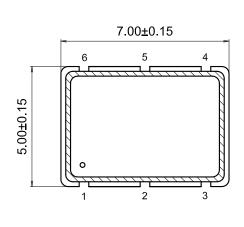
Picture of Part

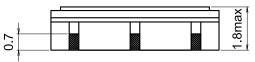


Description

The XO7500L-G2 features the use of high frequency fundamental crystals in non-PLL based circuitry to achieve the lowest possible jitter and phase noise performance. LVDS outputs exceed the requirements for SONET, XDSL, and other telecommunication standards.

Physical Dimensions & Pin Connections

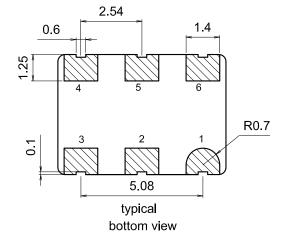


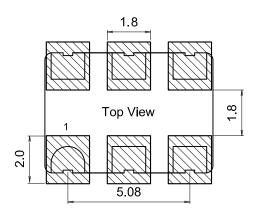


Pad1	Tri-state	Pad4	LVDS Output
Pad2	No Connection		
Pad3	Ground	Pad6	Supply Voltage

Rounded pad is pad No.1







Specification

LVDS XO (Next Generation) Frequency Range		Sym. Condition	Value			Unit	Note		
			Min.	Typ.	Max.	Cint			
		f_0	†	40	Typ.	200	MHz		
			-			•		-	
LVDS Outputs	Output High Voltage				1.430	1.600	V		
	Output Low Voltage			0.900	1.100		V		
	Output Differential		Voltage	250	350	450	MV	millivolts	
	Duty Cycle		Measured at 50% of waveform	45	50	55	%		
	Rise / Fall Time				0.20	0.40	ns	**measured at 20 to 80% of the	
								waveform	
			Start up Time		3.0	10	mS		
Power supp	alv								
Voltage	μıy	Vcc		3.150	3.300	3.450	V	2.5V +/- 5% available	
Current consumption		Icc	Current Drain is a function of frequency	0.000	16.0	27.0	mA		
			runeus or mequency						
Pad 1 Enak	ole Disable Function	1		700/		1	I		
			Voltage applied to pad 1	70% Vcc			volts	In the disabled mode, both output are enabled when Pad 1 is taken	
								Above 70% of Vcc ref to	
								Ground (threshold)	
Pad 1 Enab	ole Disable Function	1	kr. 1. 1. 1. 1.	1		200/ 17	1.	D 4	
			Voltage applied to pad 1 Oscillator circuit is always on.			30% Vcc	volts	Both outputs are disabled when Pad 1 is taken below 30% Vcc.	
			Only buffer circuit is turned OFF					Pad 1 is taken below 30% vcc.	
			Freq. OFFSET	1KHz	10KHz	100KHz			
			rieq. OFFSE1	IKIIZ	ТОКПЕ	ТООКПЕ			
Typical Pha	ise Noise as a								
Function of	Operating Frequency		125 MHz	-120	-136	-142			
			Frequency Domain Phase Jitter		0.300		PS RMS	Integrated from 12KHz to 20MHz Max.	
Environme	ntal, mechanical cond	litions.	1	1	L	1	I		
	emperature range		-40°C to +85°C maximum rang	e available	that is stan	dard			
Storage tem	perature range		-55°C to 125°C						
Humidity			85% RH; 85C; 48 hours of exp		00.11				
Vibration Shock			Mil-Std 202F, Method 204, 350			half sine w	ave		
Reflow			Mil-Std 202F, Method 213B, test condition E, 1000 GG half sine wave +260°C for 10 seconds						
			. 200 O 101 To seconds						

XO Specification		Sym. Condition	Value			Unit	Note	
			Min.	Typ.	Max.			
Frequency S	tability vs. Temp.	f_0						
			<u></u>		1		1	
F	Commercial		-40°C to +85°C, ref 25°C	-25.0		+25.0	PPM	**Best Stability available
Frequency Versus			OR	-50.0		+50.0	PPM	
Operating Temperature	Industrial		-10°C to +70°C, ref 25°C	-100.0		+100.0	PPM	
Frequency Versus Time			Frequency versus Time PER YR	-3.0		+3.0	PPM	
1								
			-					

Ordering Information

XO7500L-G2-XXX.XXXXXXV-W-Y

- 1. Field "XXX.XXXXXX " is the Output Frequency to six decimals in MHz
- 2. Field "W" is Operating Temperature Range and Freq. Stability:

a. "0" for
$$-10^{\circ}$$
C to $+70^{\circ}$ C and $+/-25$ ppm

c. "2" for
$$-10^{\circ}$$
C to $+70^{\circ}$ C and $+/-100$ ppm

3. Field "Y" is Power Supply Option

Part Number Example

XO7500L-G2-125.000000-5-0

125.000000 MHz Operating Frequency

Operating Temperature of -40°C to +85°C

+/- 100 ppm Overall Frequency Stability

2.5 V +/- 5% supply voltage

Typical Phase Noise Plot

